NSN 5961-00-256-8809

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-256-8809 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.025 inches **Overall Diameter:** 0.120 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 85.0 breakdown voltage, dc **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 ferrule and 1 connector, coaxial Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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